Circuit breaker provides overcurrent and precise overvoltage protection

Anthony Smith - June 07, 2007

Requiring only a handful of inexpensive components, the circuit breaker in Figure 1 responds to both overcurrent- and overvoltage-fault conditions. At the heart of the circuit, D₂, an adjustable, precision, shunt-voltage regulator, provides a voltage reference, comparator, and open-collector output, all integrated into a three-pin package.

![Circuit diagram]

**Figure 1** This circuit breaker provides both overvoltage and overcurrent protection. Other than the current flowing in R₃, R₄, and D₂’s cathode, the circuit draws no current from the supply in its normal untripped state.

**Figure 2** shows a simplified view of the ZR431, D₁. The voltage appearing at the reference input is compared with the internal voltage reference, V₁_Reference, nominally 2.5V. In the off state, when the reference voltage is 0V, the output transistor is off, and the cathode current is less than 0.1 µA. As the reference voltage approaches V₁_Reference, the cathode current increases slightly; when the reference voltage exceeds the 2.5V threshold, the device fully switches on, and the cathode voltage falls to approximately 2V. In this condition, the impedance between the cathode and the supply voltage
determines the cathode current; the cathode current can range from 50 µA to 100 mA.

Figure 2 In this simplified view of the ZR431, the voltage at its reference input is compared with the internal voltage reference, which is nominally 2.5V.

Under normal operating conditions, D’s output transistor is off, and the gate of P-channel MOSFET Q goes through R, such that the MOSFET is fully enhanced, allowing the load current, I_load, to flow from the supply voltage, V_S, through R into the load. Q, and current-sense resistor R, monitor the magnitude of I_load, where Q’s base-emitter voltage, V_BE, is I_load×R. For normal values of I_load, V_BE is less than the 0.6V necessary to bias Q on, such that the transistor has no effect on the voltage at the junction of R, and R. Because the input current at D’s reference input is less than 1 µA, negligible voltage drops across R, and the reference voltage is effectively equal to the voltage on R.

In the event of an overload when I_load exceeds its maximum permissible value, the increase in voltage across R results in sufficient base-emitter voltage to turn on Q. The voltage on R and, hence, the reference voltage now pull up toward V_S, causing D’s cathode voltage to fall to approximately 2V. D’s output transistor now sinks current through R, and R, thus biasing Q on. Q’s gate voltage now effectively clamps to the supply voltage through Q, and the MOSFET turns off. At the same instant, Q sources current into R through D, thereby pulling the voltage on R to a diode drop below the supply voltage. Consequently, no load current flows through R because Q’s base-emitter voltage is now 0V, has turned off. As a result, no load current flows through R, D’s output transistor latches on, and the circuit remains in its tripped state in which the load current is 0A. When choosing a value for R, ensure that Q’s base-emitter voltage is less than approximately 0.5V at the maximum permissible value of the load current.

As well as responding to overcurrent conditions, the circuit breaker also reacts to an abnormally large value of the supply voltage. When the load current lies within its normal range and Q is off, the magnitude of the supply voltage and the values of R, and R, which form a potential divider across the supply rails, determine the voltage at the reference input. In the event of an overvoltage at the supply voltage, the voltage on R exceeds the 2.5V reference level, and D’s output transistor turns on. Once again, Q turns on, MOSFET Q switches off, and the load becomes effectively isolated from the dangerous transient.

The circuit now remains in its tripped state until reset. Under these conditions, Q clamps Q’s gate-source voltage to roughly 0V, thereby protecting the MOSFET itself from excessive gate-source voltages. Ignoring the negligibly small voltage across R, you can see that the reference voltage is V_S×R/(R+R) in volts. Because D’s output turns on when the reference voltage exceeds 2.5V, you can rearrange the equation as R=([V_S/2.5]-1)×R in ohms, where V_S is the required supply-voltage trip level. For example, if R has a value of 10 kΩ, a trip voltage of 18V would require R to have a
value of 62 k\(\Omega\). When choosing values for \(R_3\) and \(R_4\) to set the desired trip voltage, ensure that they are large enough that the potential divider will not excessively load the supply. Similarly, avoid values that could result in errors due to the reference-input current.

When you first apply power to the circuit, you’ll find that capacitive, bulb-filament, motor, and similar loads having large inrush current can trip the circuit breaker, even though their normal, steady-state operating current is below the trip level that \(R_6\) sets. One way to eliminate this problem is to add capacitor \(C_2\), which slows the rate of change of the voltage at the reference input. However, although simple, this approach has a serious disadvantage in that it slows the circuit’s response time to a genuine overcurrent-fault condition.

Components \(C_1\), \(R_1\), \(R_2\), and \(Q_1\) provide an alternative solution. On power-up, \(C_1\) initially discharges, causing \(Q_1\) to turn on, thereby clamping the reference input to 0V and preventing the inrush current from tripping the circuit. \(C_1\) then charges through \(R_1\) and \(R_2\) until \(Q_1\) eventually turns off, releasing the clamp at the reference input and allowing the circuit to respond rapidly to overcurrent transients. With the values of \(C_1\), \(R_1\), and \(R_2\), the circuit allows approximately 400 msec for the inrush current to subside. Selecting other values allows the circuit to accommodate any duration of inrush current you apply to a load. Once you trip the circuit breaker, you can reset it either by cycling the power or by pressing \(S_1\), the reset switch, which connects across \(C_1\). If your application requires no inrush protection, simply omit \(C_1\), \(R_1\), \(R_2\), and \(Q_1\) and connect \(S_1\) between the reference input and 0V.

When choosing components, make sure that all parts are properly rated for the voltage and current levels they will encounter. The bipolar transistors have no special requirements, although these transistors, especially \(Q_2\) and \(Q_3\), should have high current gain, \(Q_4\) should have low on-resistance, and \(Q_4\)’s maximum drain-to-source and gate-to-source voltages must be commensurate with the maximum value of supply voltage. You can use almost any small-signal diode for \(D_1\). As a precaution, it may be necessary to fit zener diodes \(D_3\) and \(D_4\) to protect \(D_2\) if extremely large transient voltages are likely.

Although this circuit uses the 431 device, which is widely available from different manufacturers, for \(D_2\), not all of these parts behave in exactly the same way. For example, tests on a Texas Instruments TL431CLP and a Zetex ZR431CL reveal that the cathode current is 0A for both devices when the reference voltage is 0V. However, gradually increasing the reference voltage from 2.2 to 2.45V produces a change in cathode current ranging from 220 to 380 \(\mu\)A for the TL431CLP and 23 to 28 \(\mu\)A for the ZR431CL—roughly a factor of 10 difference between the two devices. You must take this difference in the magnitude of the cathode current into account when selecting values for \(R_7\) and \(R_8\).

The type of device you use for \(D_2\) and the values you select for \(R_7\) and \(R_8\) can also have an effect on response time. A test circuit with a TL431CLP, in which \(R_7\) is 1 k\(\Omega\) and \(R_8\) is 4.7 k\(\Omega\), responds within 550 nsec to an overcurrent transient. Replacing the TL431CLP with a ZR431CL results in a response time of approximately 1 \(\mu\)sec. Increasing \(R_7\) and \(R_8\) by an order of magnitude to 10 and 47 k\(\Omega\), respectively, produces a response time of 2.8 \(\mu\)sec. Note that the relatively large cathode current of the TL431CLP requires correspondingly small values of \(R_7\) and \(R_8\).

To set the overvoltage-trip level at 18V, \(R_3\) and \(R_4\) must have values of 62 and 10 k\(\Omega\), respectively. The test circuit then produces the following results: Using a TL431CLP for \(D_2\), the circuit trips at 17.94V, and, using a ZR431CL for \(D_2\), the trip level is 18.01V. Depending on \(Q_4\)’s base-emitter voltage, the overcurrent-detection mechanism is less precise than the overvoltage function. However, the overcurrent-detection accuracy greatly improves by replacing \(R_8\) and \(Q_2\) with a high-side current-sense amplifier that generates a ground-referred current proportional to load current. These devices are available from Linear Technology, Maxim, Texas Instruments, Zetex, and others.
The circuit breaker should prove useful in applications such as automotive systems that require overcurrent detection to protect against faulty loads and that also need overvoltage protection to shield sensitive circuitry from high-energy-load-dump transients. Other than the small current flowing in $R_3$ and $R_4$ and the current in $D_2$’s cathode, the circuit draws no current from the supply in its normal, untripped state.

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